

DTC114EET1 Series

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-75/SOT-416 Package Can be Soldered Using Wave or Reflow
- The Modified Gull-Winged Leads Absorb Thermal Stress During Soldering Eliminating the Possibility of Damage to the Die
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Total Device Dissipation, FR-4 Board (Note 1) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	200 1.6	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	$^\circ\text{C/W}$
Total Device Dissipation, FR-4 Board (Note 2) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

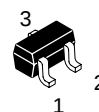
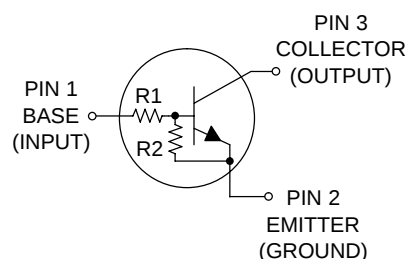
1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0×1.0 Inch Pad



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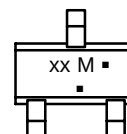
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NPN SILICON BIAS RESISTOR TRANSISTORS



SC-75 (SOT-416)
CASE 463
STYLE 1

MARKING DIAGRAM



- xx = Specific Device Code
xx = (Refer to page 2)
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

DTC114EET1 Series

ORDERING INFORMATION, DEVICE MARKING and RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Package	Shipping [†]
DTC114EET1	8A	10	10	SC-75/SOT-416	3000 Tape & Reel
DTC114EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC124EET1	8B	22	22	SC-75/SOT-416	3000 Tape & Reel
DTC124EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC144EET1	8C	47	47	SC-75/SOT-416	3000 Tape & Reel
DTC144EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC114YET1	8D	10	47	SC-75/SOT-416	3000 Tape & Reel
DTC114YET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC114TET1	94	10	∞	SC-75/SOT-416	3000 Tape & Reel
DTC114TET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC143TET1	8F	4.7	∞	SC-75/SOT-416	3000 Tape & Reel
DTC143TET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC123EET1	8H	2.2	2.2	SC-75/SOT-416	3000 Tape & Reel
DTC123EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC143EET1	8J	4.7	4.7	SC-75/SOT-416	3000 Tape & Reel
DTC143EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC143ZET1	8K	4.7	47	SC-75/SOT-416	3000 Tape & Reel
DTC143ZET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC124XET1	8L	22	47	SC-75/SOT-416	3000 Tape & Reel
DTC124XET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC123JET1	8M	2.2	47	SC-75/SOT-416	3000 Tape & Reel
DTC123JET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC115EET1	8N	100	100	SC-75/SOT-416	3000 Tape & Reel
DTC115EET1G				SC-75/SOT-416 (Pb-Free)	3000 Tape & Reel
DTC144WET1	8P	47	22	SC-75/SOT-416	3000 Tape & Reel
DTC144WET1G				SC-75/SOT-416	3000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DTC114EET1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$)	I_{CBO}	–	–	100	nAdc
Collector–Emitter Cutoff Current ($V_{CE} = 50\text{ V}$, $I_B = 0$)	I_{CEO}	–	–	500	nAdc
Emitter–Base Cutoff Current ($V_{EB} = 6.0\text{ V}$, $I_C = 0$)	I_{EBO}	–	–	0.5	mAdc
DTC114EET1		–	–	0.2	
DTC124EET1		–	–	0.1	
DTC144EET1		–	–	0.2	
DTC114YET1		–	–	0.9	
DTC114TET1		–	–	1.9	
DTC143TET1		–	–	2.3	
DTC123EET1		–	–	1.5	
DTC143EET1		–	–	0.18	
DTC143ZET1		–	–	0.13	
DTC124XET1		–	–	0.2	
DTC123JET1		–	–	0.05	
DTC115EET1		–	–	0.13	
DTC144WET1		–	–		
Collector–Base Breakdown Voltage ($I_C = 10\text{ }\mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 3) ($I_C = 2.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	50	–	–	Vdc

ON CHARACTERISTICS (Note 3)

DC Current Gain ($V_{CE} = 10 \text{ V}$, $I_C = 5.0 \text{ mA}$)	DTC114EET1 DTC124EET1 DTC144EET1 DTC114YET1 DTC114TET1 DTC143TET1 DTC123EET1 DTC143EET1 DTC143ZET1 DTC124XET1 DTC123JET1 DTC115EET1 DTC144WET1	h_{FE}	35 60 80 80 160 160 8.0 15 80 80 80 80 80	60 100 140 140 350 350 15 30 200 150 140 150 140	- - - - - - - - - - - - -	
Collector-Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.3 \text{ mA}$) ($I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$) DTC123EET1 ($I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$) DTC143TET1/DTC114TET1/ DTC143EET1/DTC143ZET1/DTC124XET1		$V_{CE(sat)}$	-	-	0.25	Vdc
Output Voltage (on) ($V_{CC} = 5.0 \text{ V}$, $V_B = 2.5 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$) ($V_{CC} = 5.0 \text{ V}$, $V_B = 3.5 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$) ($V_{CC} = 5.0 \text{ V}$, $V_B = 5.5 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$) ($V_{CC} = 5.0 \text{ V}$, $V_B = 4.0 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$)	DTC114EET1 DTC124EET1 DTC114YET1 DTC114TET1 DTC143TET1 DTC123EET1 DTC143EET1 DTC143ZET1 DTC124XET1 DTC123JET1 DTC144EET1 DTC115EET1 DTC144WET1	V_{OL}	- - - - - - - - - - - - -	- - - - - - - - - - - - -	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	Vdc
Output Voltage (off) ($V_{CC} = 5.0 \text{ V}$, $V_B = 0.5 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$) ($V_{CC} = 5.0 \text{ V}$, $V_B = 0.25 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$)	DTC143TET1 DTC143ZET1 DTC114TET1	V_{OH}	4.9	-	-	Vdc

3. Pulse Test: Pulse Width $300\ \mu\text{s}$, Duty Cycle $< 2.0\%$

DTC114EET1 Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Resistor					
TC114EET1	R1	7.0	10	13	k Ω
DTC124EET1		15.4	22	28.6	
DTC144EET1		32.9	47	61.1	
DTC114YET1		7.0	10	13	
DTC114TET1		7.0	10	13	
DTC143TET1		3.3	4.7	6.1	
DTC123EET1		1.5	2.2	2.9	
DTC143EET1		3.3	4.7	6.1	
DTC143ZET1		3.3	4.7	6.1	
DTC124XET1		15.4	22	28.6	
DTC123JET1		1.54	2.2	2.86	
DTC115EET1		70	100	130	
DTC144WET1		32.9	47	61.1	
Resistor Ratio					
DTC114EET1/DTC124EET1/DTC144EET1/ DTC115EET1	R_1/R_2	0.8	1.0	1.2	
DTC114YET1		0.17	0.21	0.25	
DTC143TET1/DTC114TET1		—	—	—	
DTC123EET1/DTC143EET1		0.8	1.0	1.2	
DTC143ZET1		0.055	0.1	0.185	
DTC124XET1		0.38	0.47	0.56	
DTC123JET1		0.038	0.047	0.056	
DTC144WET1D		1.7	2.1	2.6	

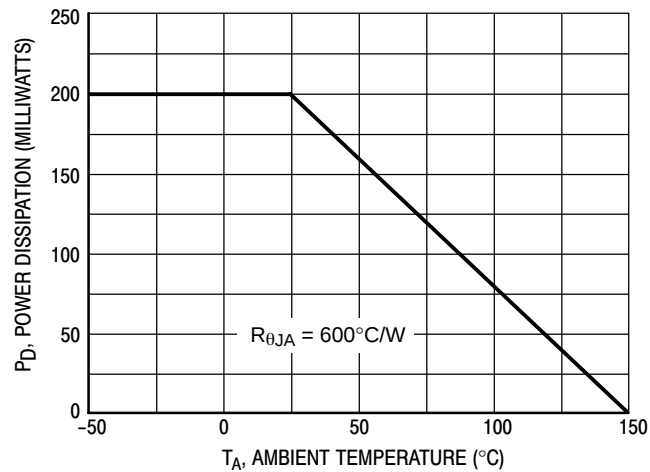


Figure 1. Derating Curve

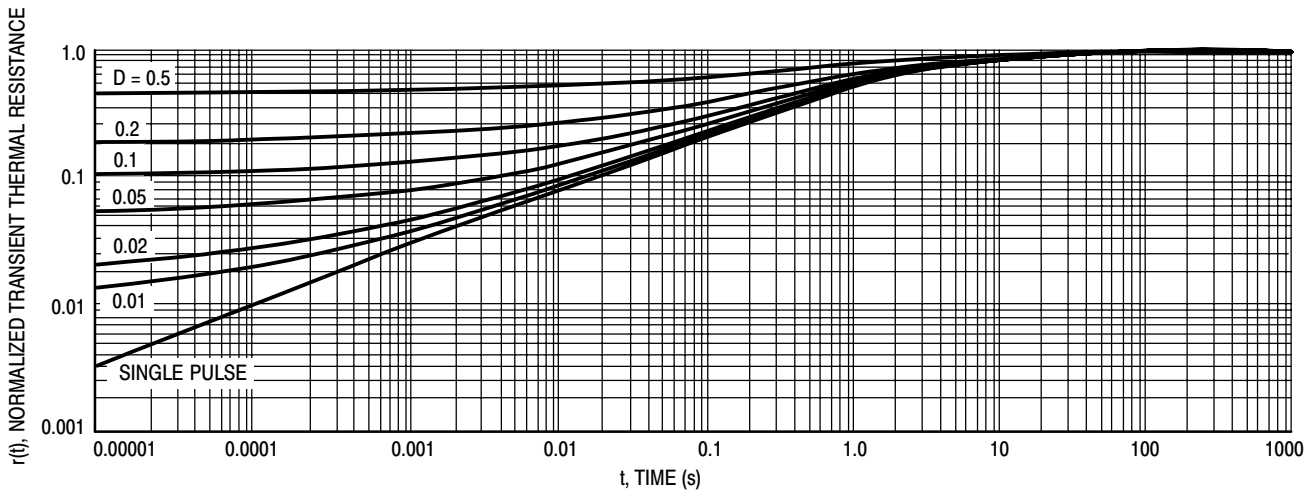


Figure 2. Normalized Thermal Response

DTC114EET1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – DTC114EET1

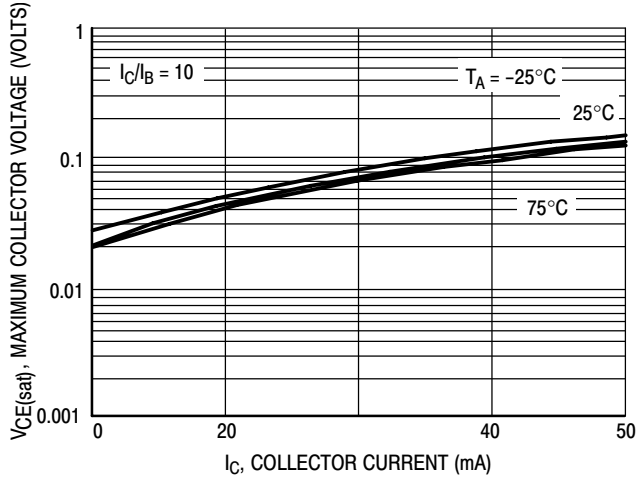


Figure 3. $V_{CE(sat)}$ versus I_C

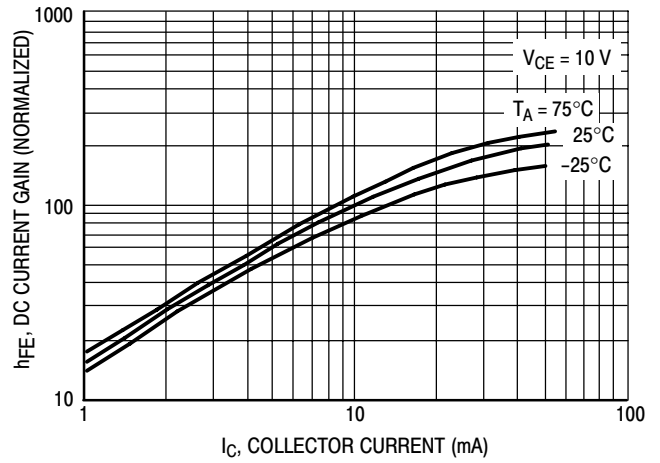


Figure 4. DC Current Gain

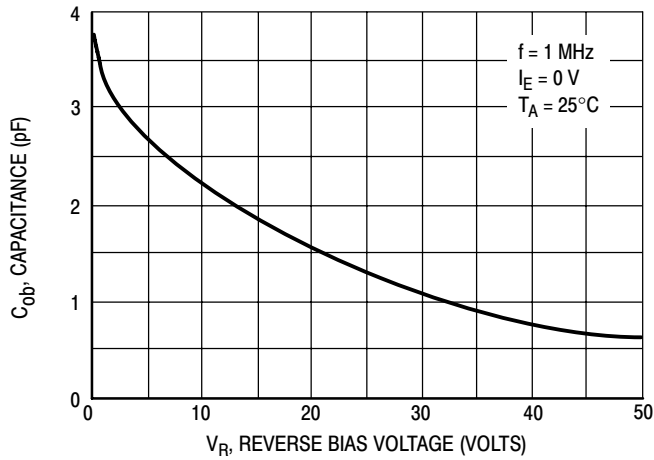


Figure 5. Output Capacitance

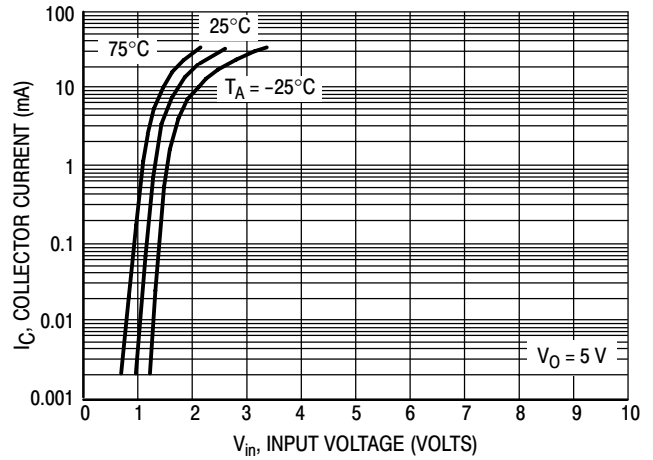


Figure 6. Output Current versus Input Voltage

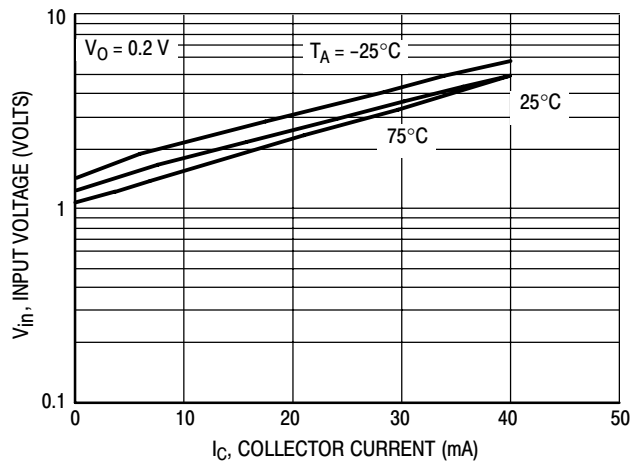


Figure 7. Input Voltage versus Output Current

DTC114EET1 Series

TYPICAL ELECTRICAL CHARACTERISTICS - DTC123EET1

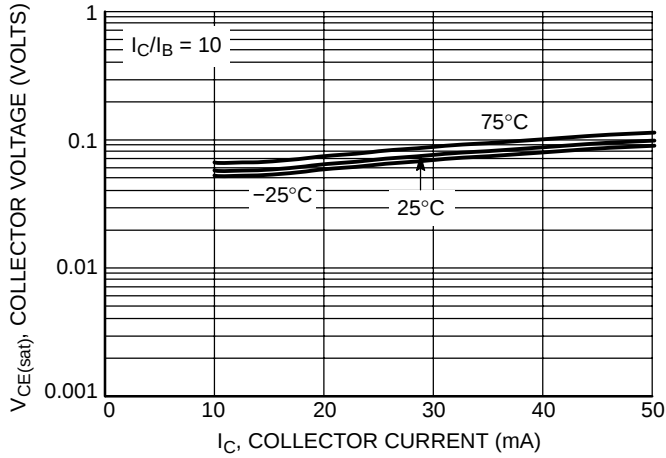


Figure 8. $V_{CE(sat)}$ versus I_C

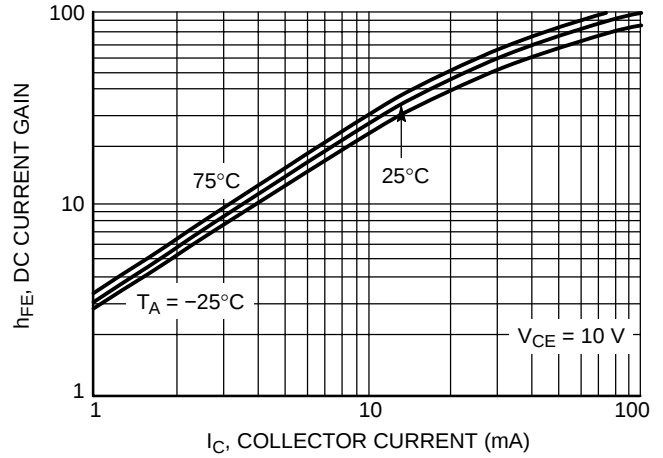


Figure 9. DC Current Gain

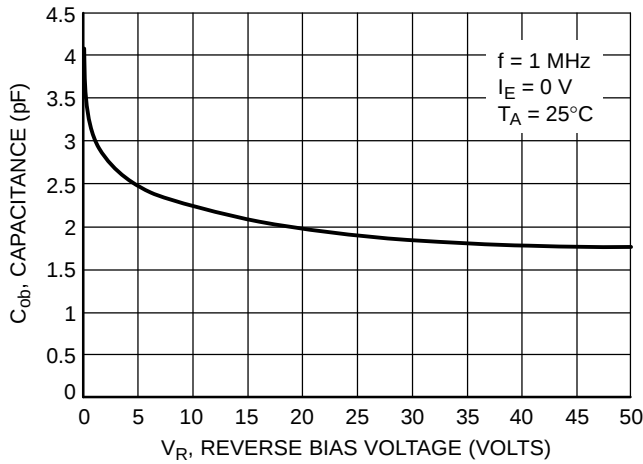


Figure 10. Output Capacitance

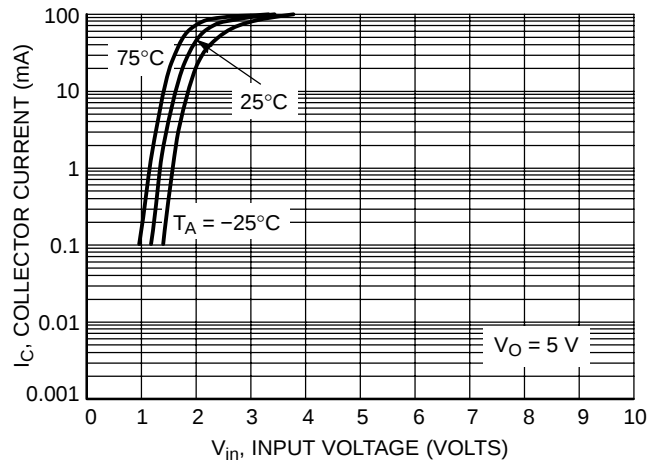


Figure 11. Output Current versus Input Voltage

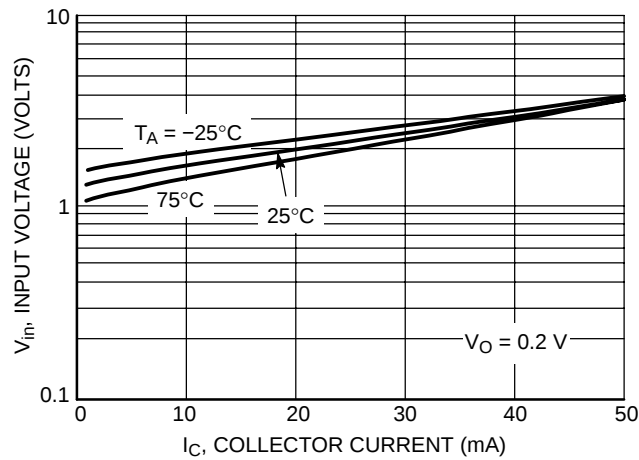


Figure 12. Input Voltage versus Output Current

DTC114EET1 Series

TYPICAL ELECTRICAL CHARACTERISTICS - DTC124EET1

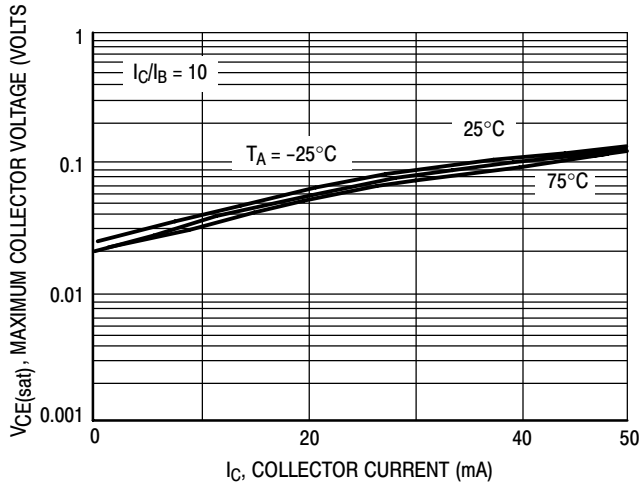


Figure 13. $V_{CE(sat)}$ versus I_C

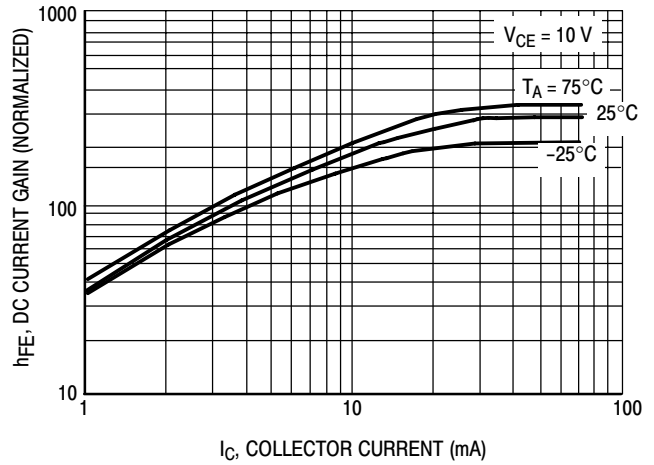


Figure 14. DC Current Gain

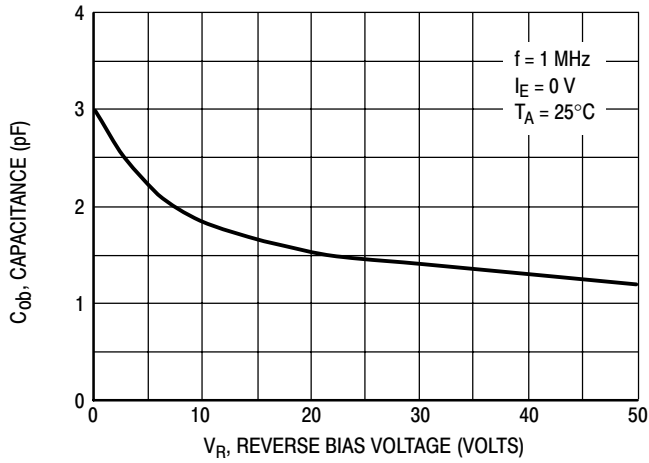


Figure 15. Output Capacitance

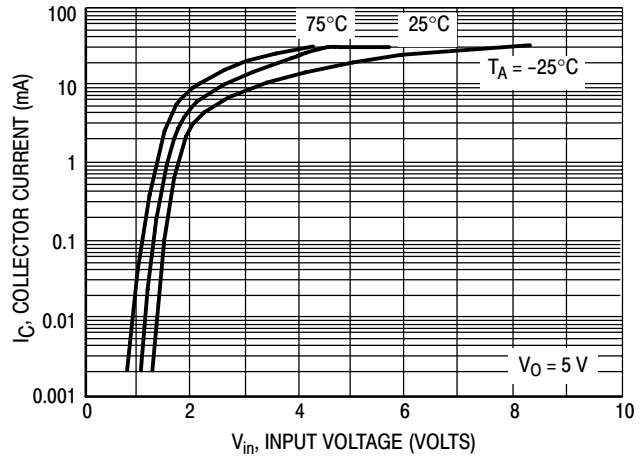


Figure 16. Output Current versus Input Voltage

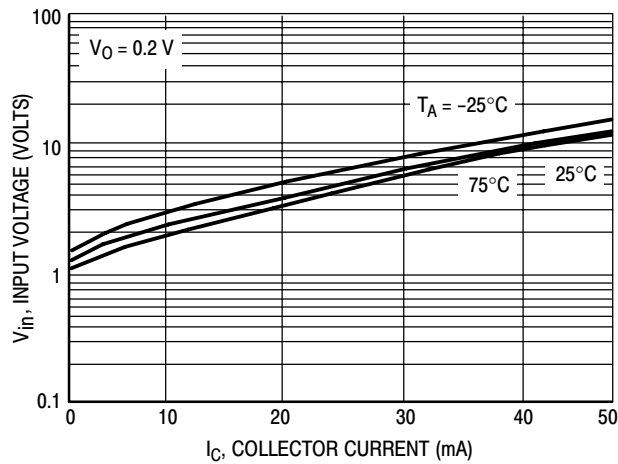


Figure 17. Input Voltage versus Output Current

DTC114EET1 Series

TYPICAL ELECTRICAL CHARACTERISTICS - DTC144EET1

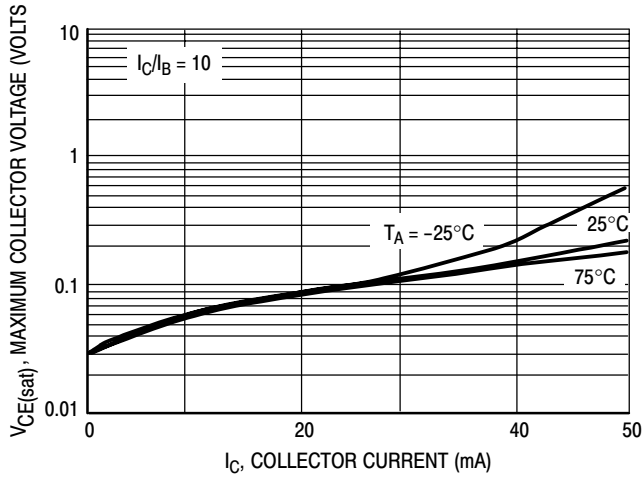


Figure 18. $V_{CE(sat)}$ versus I_C

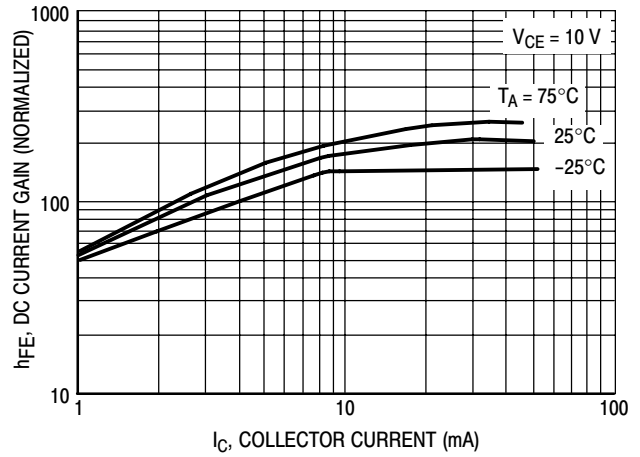


Figure 19. DC Current Gain

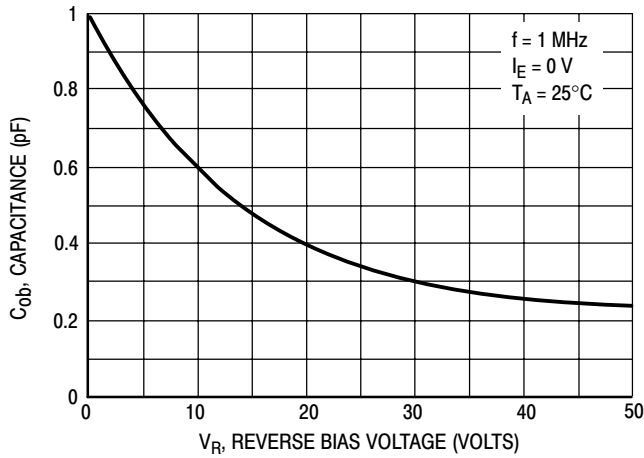


Figure 20. Output Capacitance

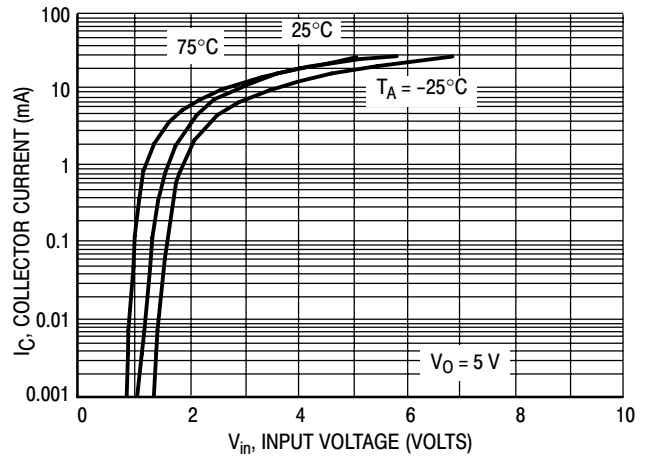


Figure 21. Output Current versus Input Voltage

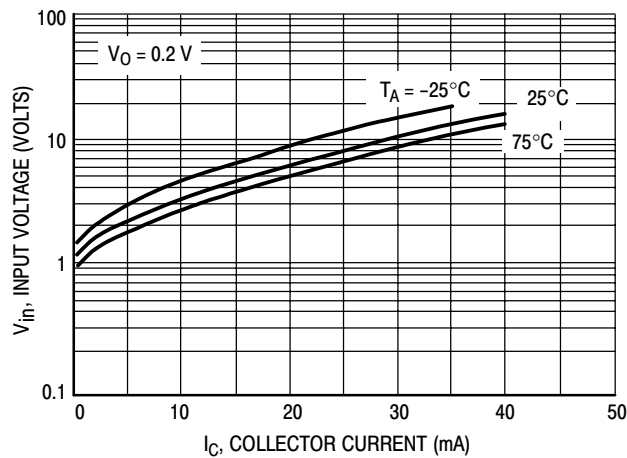


Figure 22. Input Voltage versus Output Current

DTC114EET1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – DTC114YET1

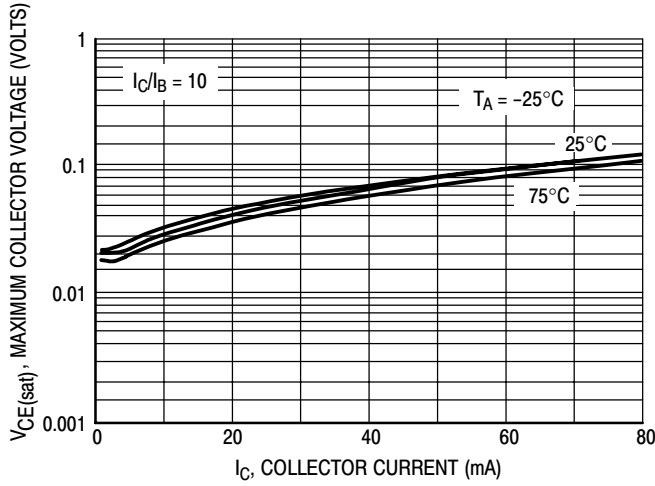


Figure 23. $V_{CE(sat)}$ versus I_C

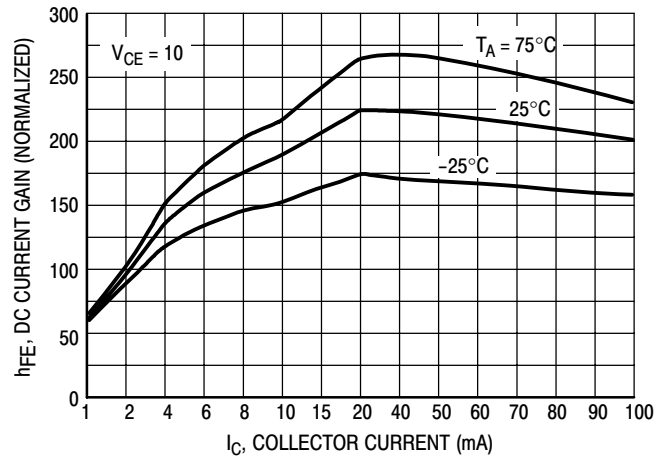


Figure 24. DC Current Gain

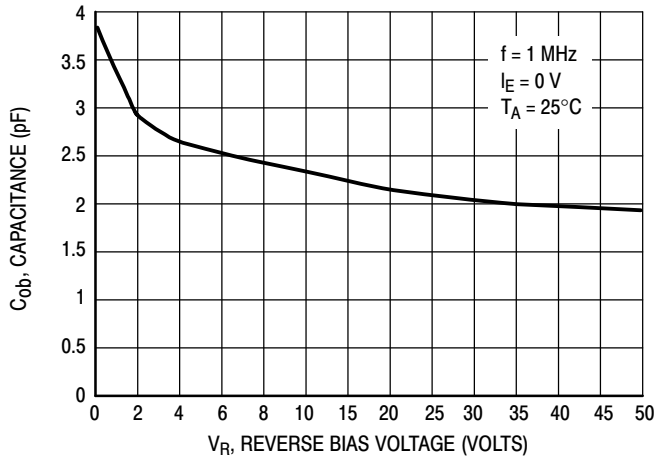


Figure 25. Output Capacitance

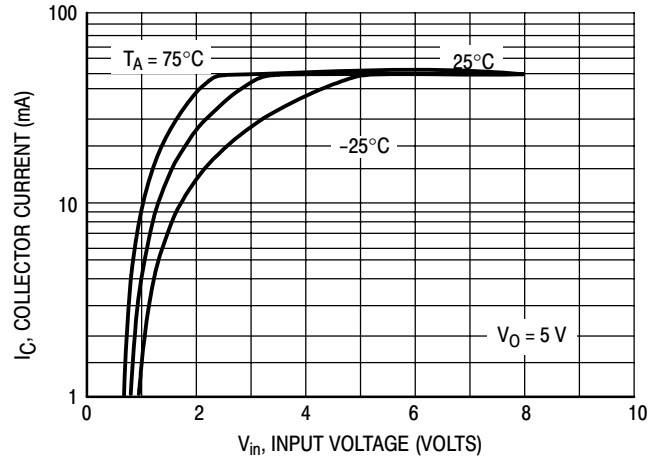


Figure 26. Output Current versus Input Voltage

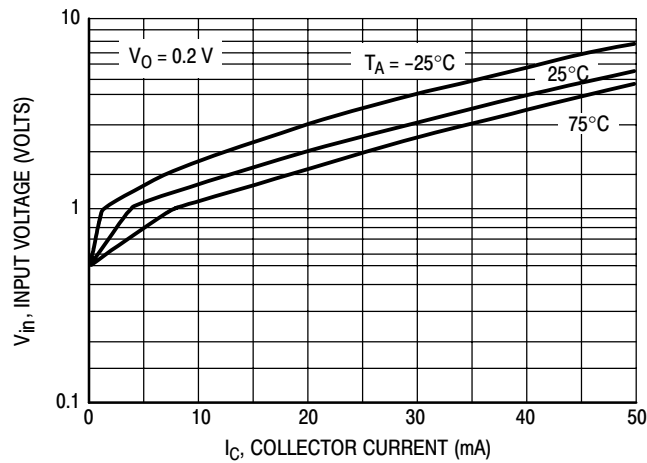


Figure 27. Input Voltage versus Output Current

DTC114EET1 Series

TYPICAL APPLICATIONS FOR NPN BRTs

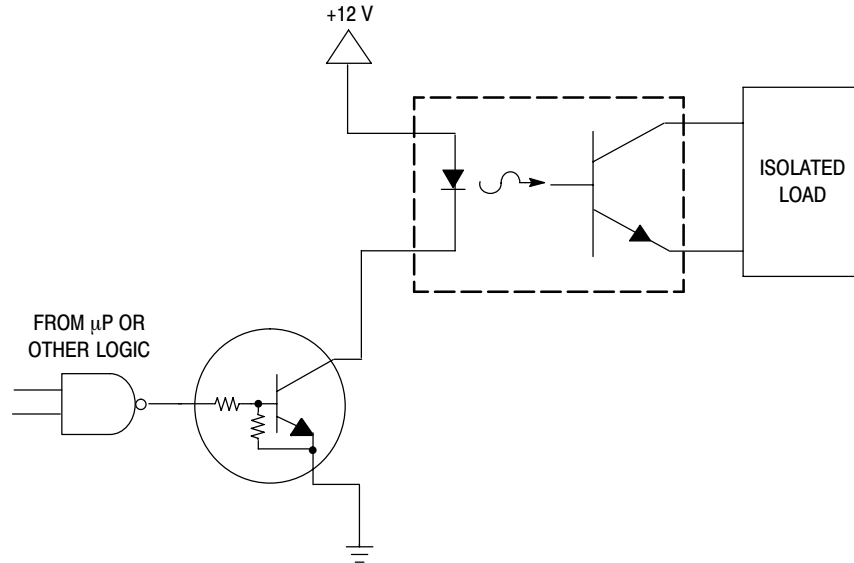


Figure 28. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

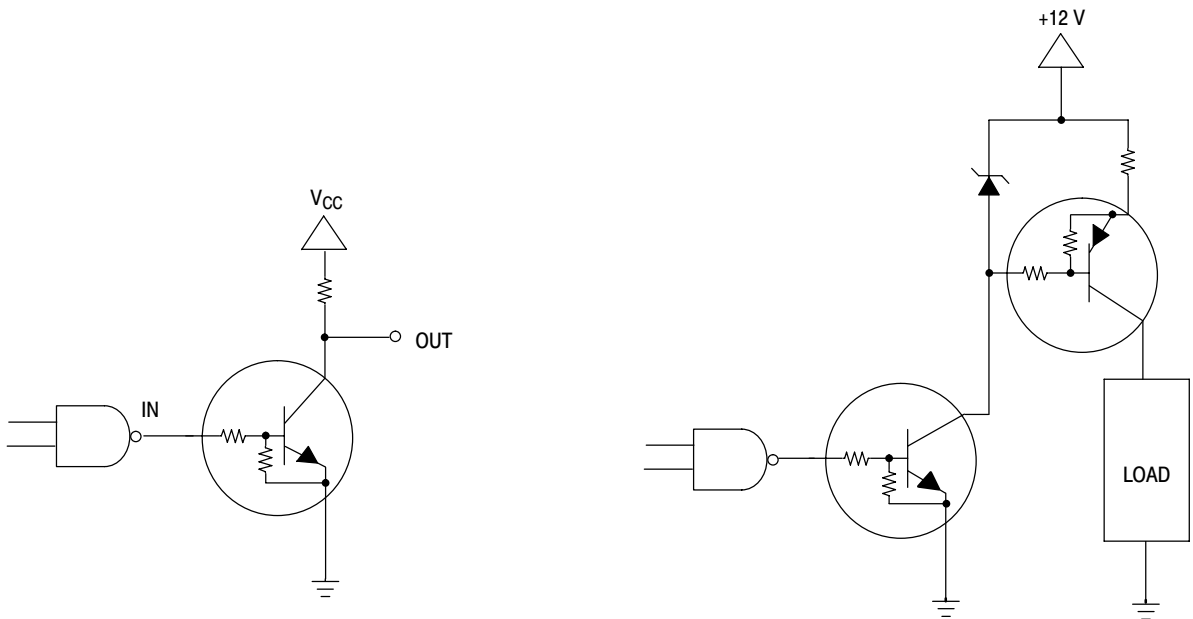


Figure 29. Open Collector Inverter:
Inverts the Input Signal

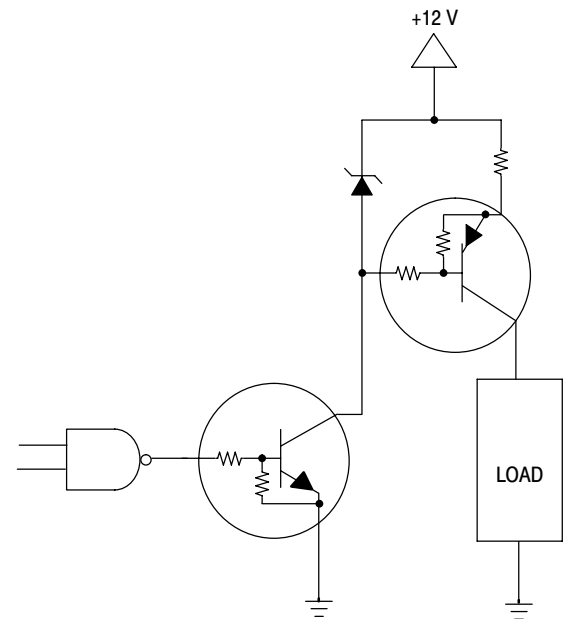
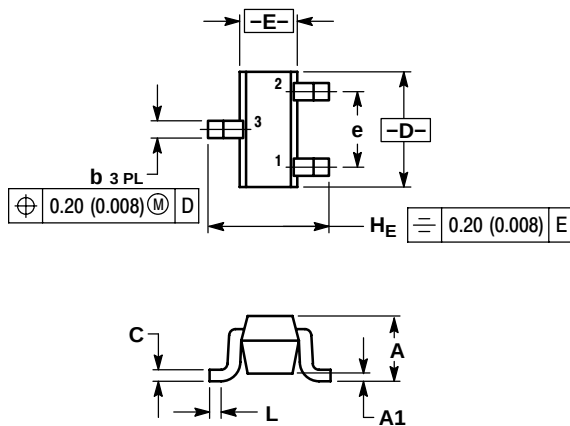


Figure 30. Inexpensive, Unregulated Current Source

DTC114EET1 Series

PACKAGE DIMENSIONS

SC-75/SOT-416
CASE 463-01
ISSUE F

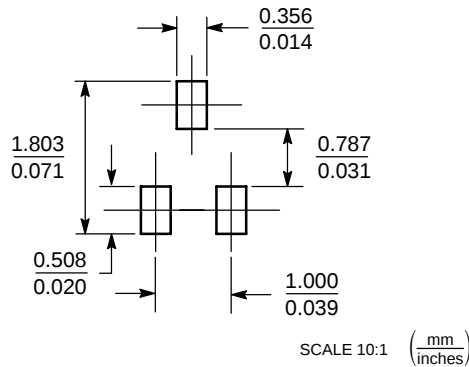


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
C	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
e	1.00 BSC			0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
H _E	1.50	1.60	1.70	0.061	0.063	0.065

- STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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